

SF51G THRU SF58G

5.0A Axial Leaded Super Fast Rectifiers-50-600V

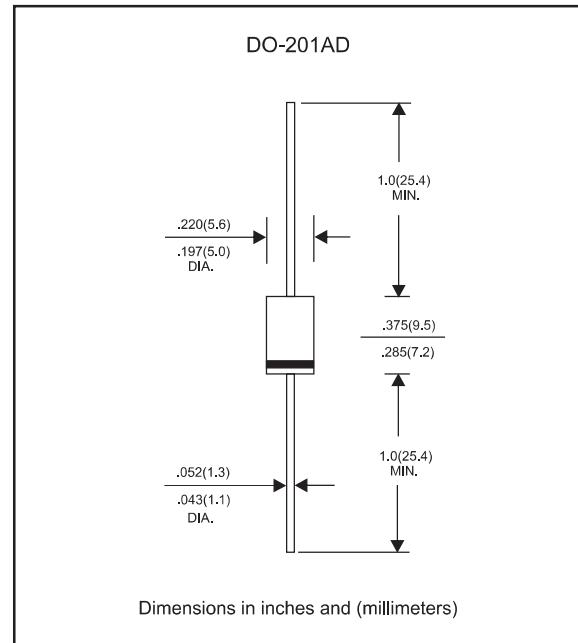
Features

- Low reverse leakage current
- Low forward drop down voltage & high current capability
- High surge current capability
- Super fast switching speed for high efficiency
- Glass passivated chip junction
- High Reliability
- Lead-free parts for green partner, meet RoHS requirements
- Suffix "-H" indicates Halcon free parts, ex. SF51G-H.

Mechanical data

- Epoxy : UL94-V0 rated flame retardant
- Case : Molded plastic, DO-201AD
- Lead : Axial leads, solderable per MIL-STD-202, Method 208 guaranteed
- Polarity: Color band denotes cathode end
- Mounting Position : Any

Package outline

Maximum ratings and Electrical Characteristics (AT $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	Ambient temperature = 55°C	I_O			5.0	A
Forward surge current	8.3ms single half sine-wave (JEDEC method)	I_{FSM}			150	A
Reverse current	$V_R = V_{RRM}$ $T_J = 25^\circ\text{C}$	I_R			5.0	μA
	$V_R = V_{RRM}$ $T_J = 125^\circ\text{C}$				100	
Thermal resistance	Junction to ambient	$R_{\theta JA}$		30		$^\circ\text{C/W}$
Diode junction capacitance	$f=1\text{MHz}$ and applied 4V DC reverse voltage	C_J		80		pF
Storage temperature		T_{STG}	-65		+175	$^\circ\text{C}$

SYMBOLS	V _{RRM} ^{*1} (V)	V _{RMS} ^{*2} (V)	V _R ^{*3} (V)	V _F ^{*4} (V)	t _{rr} ^{*5} (ns)	Operating temperature T _J , (°C)
SF51G	50	35	50	0.95	35	-55 to +150
SF52G	100	70	100			
SF53G	150	105	150			
SF54G	200	140	200			
SF55G	300	210	300	1.25		
SF56G	400	280	400			
SF57G	500	350	500	1.70		
SF58G	600	420	600			

*1 Repetitive peak reverse voltage

*2 RMS voltage

*3 Continuous reverse voltage

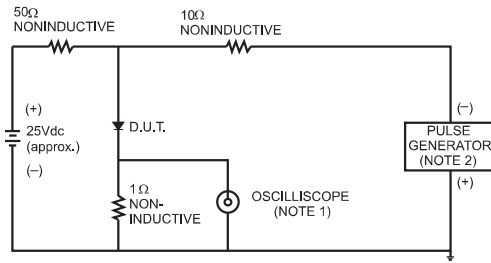
*4 Maximum forward voltage@ $I_F=5.0\text{A}$

*5 Maximum Reverse recovery time, note 1

Note 1. Reverse recovery time test condition, $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$

Rating and characteristic curves (SF51G THRU SF58G)

FIG.1- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm, 22pF.
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

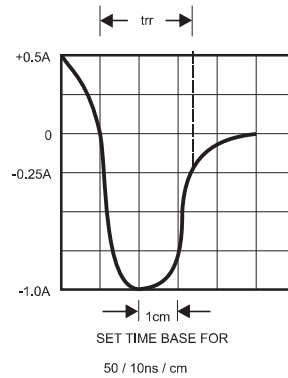


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

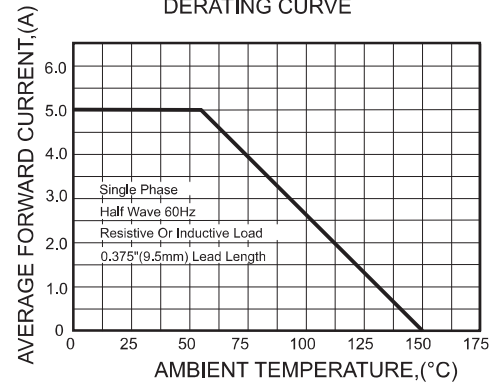


FIG. 3 - TYPICAL FORWARD CHARACTERISTICS

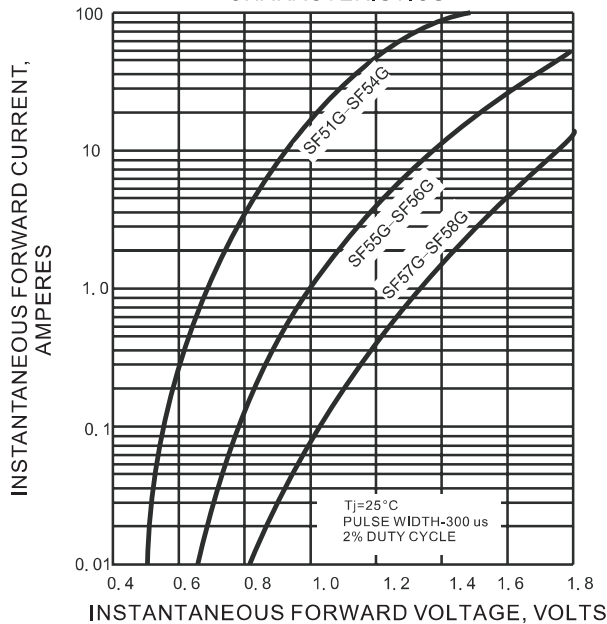


FIG.4-TYPICAL REVERSE CHARACTERISTICS

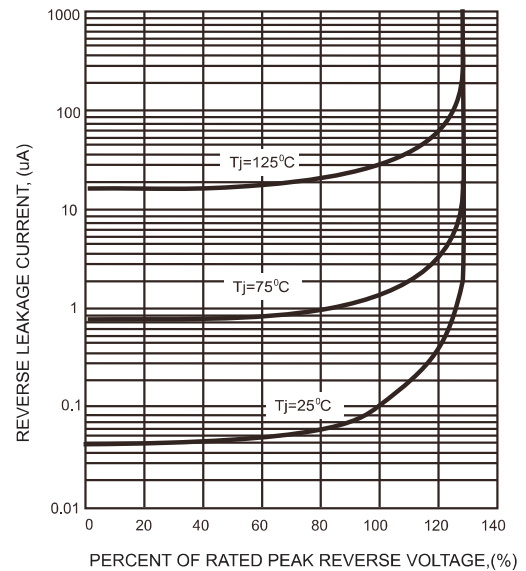


FIG.5-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

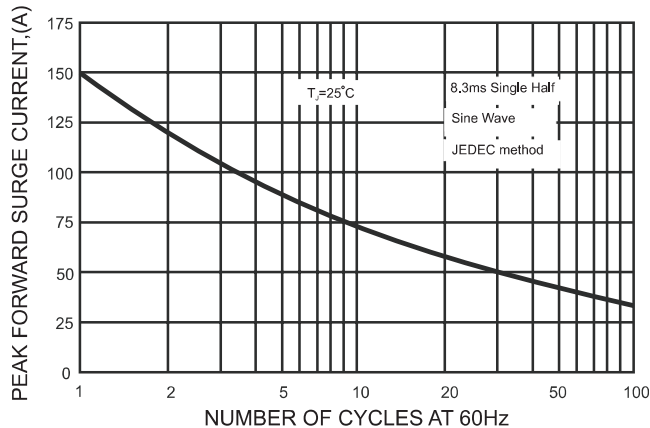
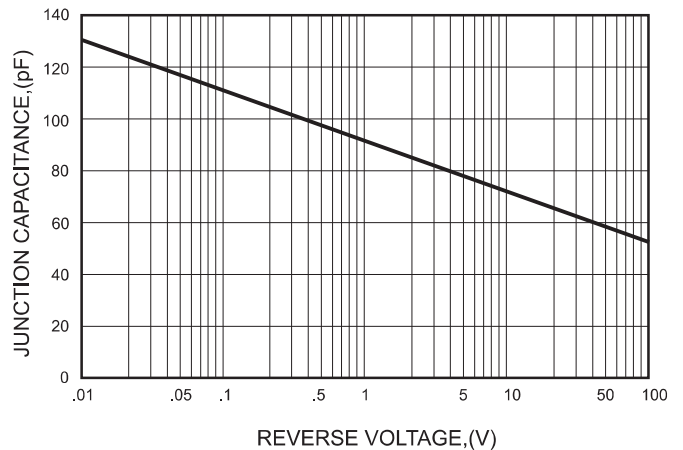


FIG.6-TYPICAL JUNCTION CAPACITANCE



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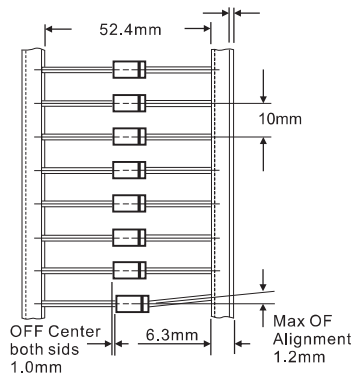
Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode	1  2	1  2

Marking

Type number	Marking code
SF51G	SF51G
SF52G	SF52G
SF53G	SF53G
SF54G	SF54G
SF55G	SF55G
SF56G	SF56G
SF57G	SF57G
SF58G	SF58G

Taping specifications for AXIAL devices



AMMO PACKING

DEVICE CASE TYPE	Q'TY 1 (PCS / BOX)	INNER BOX SIZE (m/m)	CARTON SIZE (m/m)	Q'TY 2 (PCS / CARTON)	APPROX. CROSS WEIGHT(kg)
DO-201AD	1,250	252 * 78 * 150	405 * 270 * 320	12,500	14.0

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